

L Number	Hits	Search Text	DB	Time stamp
1	69435	silicon adj nitride	USPAT; US-PGPUB	2004/01/14 17:33
2	4221	"Si.sub.3N.sub.4"	USPAT; US-PGPUB	2004/01/14 17:34
3	1251900	opening\$1	USPAT; US-PGPUB	2004/01/14 17:34
4	844838	hole\$1	USPAT; US-PGPUB	2004/01/14 17:34
5	42426	trench\$2	USPAT; US-PGPUB	2004/01/14 17:34
6	26206	wet adj etch\$3	USPAT; US-PGPUB	2004/01/14 17:35
9	328	438/756.ccls.	USPAT; US-PGPUB	2004/01/14 18:20
10	146	438/757.ccls.	USPAT; US-PGPUB	2004/01/14 18:37
11	124	438/751.ccls.	USPAT; US-PGPUB	2004/01/14 18:48
13	246	438/740.ccls.	USPAT; US-PGPUB	2004/01/14 18:58
16	17204	etch\$3 adj stop\$4	USPAT; US-PGPUB	2004/01/14 19:18
17	115	438/740.ccls. and (((silicon adj nitride) or "Si.sub.3N.sub.4") same (etch\$3 adj stop\$4))	USPAT; US-PGPUB	2004/01/14 19:18
18	59351	silicon adj oxide	USPAT; US-PGPUB	2004/01/14 19:19
19	122089	"SiO.sub.2"	USPAT; US-PGPUB	2004/01/14 19:19
20	3	438/740.ccls. and ((wet adj etch\$3) same (etch\$3 adj stop\$4) same ((silicon adj oxide) or "SiO.sub.2"))	USPAT; US-PGPUB	2004/01/14 19:20
7	1485	((silicon adj nitride) or "Si.sub.3N.sub.4") same (opening\$1 or hole\$1 or trench\$2) same (wet adj etch\$3)	USPAT; US-PGPUB	2004/01/14 19:24